
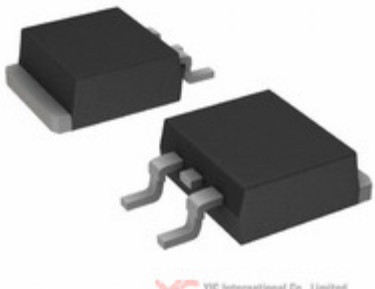
	<p>SUD40N02-08-E3</p>
	<p>Hersteller-Teilenummer: SUD40N02-08-E3</p> <hr/> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 20V 40A TO252</p> <hr/> <p>Datenblätter:  SUD40N02-08-E3.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 35070 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SUD40N02-08-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 20V 40A TO252
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	35070 pcs Stock
detaillierte Beschreibung	N-Channel 20V 40A (Tc) 8.3W (Ta), 71W (Tc) Surface
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252, (D-Pak)
Verlustleistung (max)	8.3W (Ta), 71W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	40A (Tc)
Rds On (Max) @ Id, Vgs	8.5 mOhm @ 20A, 4.5V
VGS (th) (Max) @ Id	600mV @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	35nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	2660pF @ 20V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 4.5V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

SUD40N02-08-E3 ist neu im Original, Suche SUD40N02-08-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SUD40N02-08-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SUD40N02-08-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SUD35N10-26P-T4GE3 Vishay / Siliconix MOSFET N-CH 100V 35A TO252</p>	 <p>SUD35N10-26P-GE3 Vishay / Siliconix MOSFET N-CH 100V 35A DPAK</p>	 <p>SUD40151EL-GE3 Electro-Films (EFI) / Vishay MOSFET P-CHAN 40V TO-252</p>	 <p>SUD40N02-3M3P-E3 Vishay / Siliconix MOSFET N-CH 20V 24.4A TO252</p>
 <p>SUD35N10-26P-T4GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 100V 35A TO252</p>	 <p>SUD40N02-3M3P Original SUD40N02-3M3P Original</p>	 <p>SUD40N03-18P VISHAY SUD40N03-18P VISHAY</p>	 <p>SUD40N03-18P-E3 VISHAY SUD40N03-18P-E3 VISHAY</p>

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| <ul style="list-style-type: none"> ⊛ SUD23N06-31_11 ⊣ SUD25N05-45L ⊛ SUD25N15-52-E3 D SUD30N06-30 ⇒ SUD35N10-26P-E3 ↔ SUD40N02-3M3P ⊛ SUD40N04 ⊣ SUD40N06-25L ⊛ SUD40N08-16-T4-E3 ↔ SUD40P03-20 | <ul style="list-style-type: none"> ↔ SUD25N04-25 ⊛ SUD25N06-45L ⊣ SUD25N15-52-E3 ⊛ SUD35N05-26L ↔ SUD35N10-26P-E3 ⇒ SUD40N02-3M3P-E3 D SUD40N04-10A ⊛ SUD40N08-16 ⊣ SUD40N08-16_08 ⊛ SUD42N03-3M9P | <ul style="list-style-type: none"> ⇒ SUD25N04-25-T4-E3 D SUD25N06-45L-E3 ⊛ SUD30N03-30 ⊣ SUD35N05-26L-E3 ⊛ SUD35N10-26P-GE3 D SUD40N02-3M3P-E3 ⇒ SUD40N04-10A-E3 ↔ SUD40N08-16-E3 ⊛ SUD40N10-25 ⊣ SUD42N03-3M9P-GE3 | <ul style="list-style-type: none"> D SUD25N04-25-T4-E3 ⇒ SUD25N06-45L-GE3 ↔ SUD30N04-10 ⊛ SUD35N05-26L-E3 ⊣ SUD35N10-26P-GE3 ⊛ SUD40N03-18P ↔ SUD40N04-10A-E3 ⇒ SUD40N08-16-E3 D SUD40N10-25-E3 ⊛ SUD42N03-3M9P-GE3 | <ul style="list-style-type: none"> ⇒ SUD25N05-13L ⇒ SUD25N15-52 ⇒ SUD30N04-10-E3 ⇒ SUD35N10-26P ⇒ SUD40N02-08-E3 ⊣ SUD40N03-18P-E3 ⇒ SUD40N04-20 ⇒ SUD40N08-16-E3. ⇒ SUD40N10-25-E3 ⇒ SUD45N03-09 |
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